

Measurement of charge collection in p-type microstrip sensors with SCT128 chip

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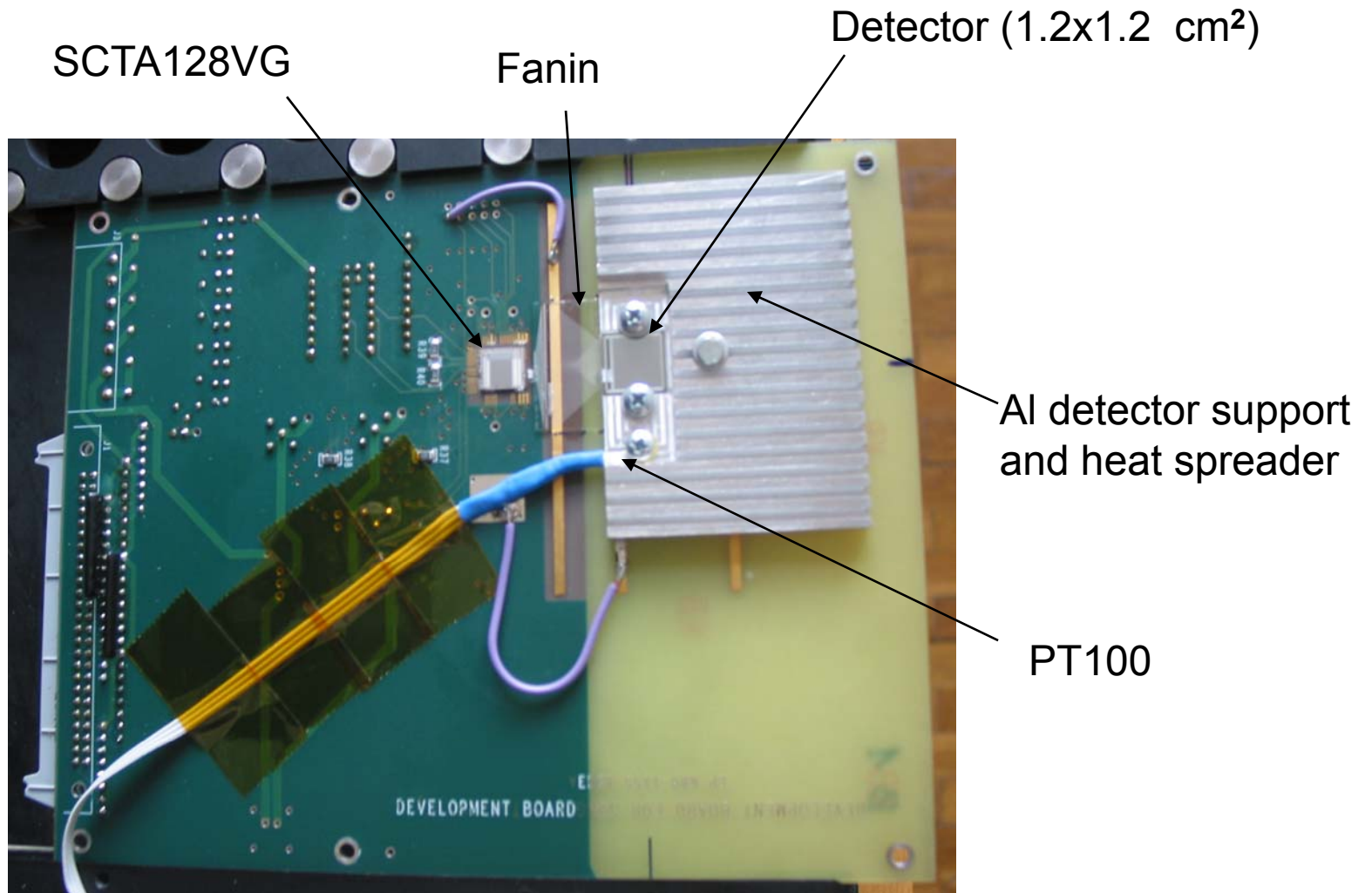


Setup for measurements with SCT128 chip was built in Ljubljana:

- SCTA128VG chip
- drawings of test pcb from CERN (thanks to [Jan Kaplon](#))
- VME module SEQSI (for clock, commands...)
- Tektronix digital scope for data acquisition
- Cambridge LabView software for chip control (thanks to [Dave Robinson](#))
- data acquisition software (thanks to [G. Kramberger](#))
- pitch adapters from Freiburg (thanks to [Uli Parzefal](#))
- coincidence circuit made by [Erik Margan](#)
- ^{90}Sr source, photomultiplier, scintillator, power supplies....



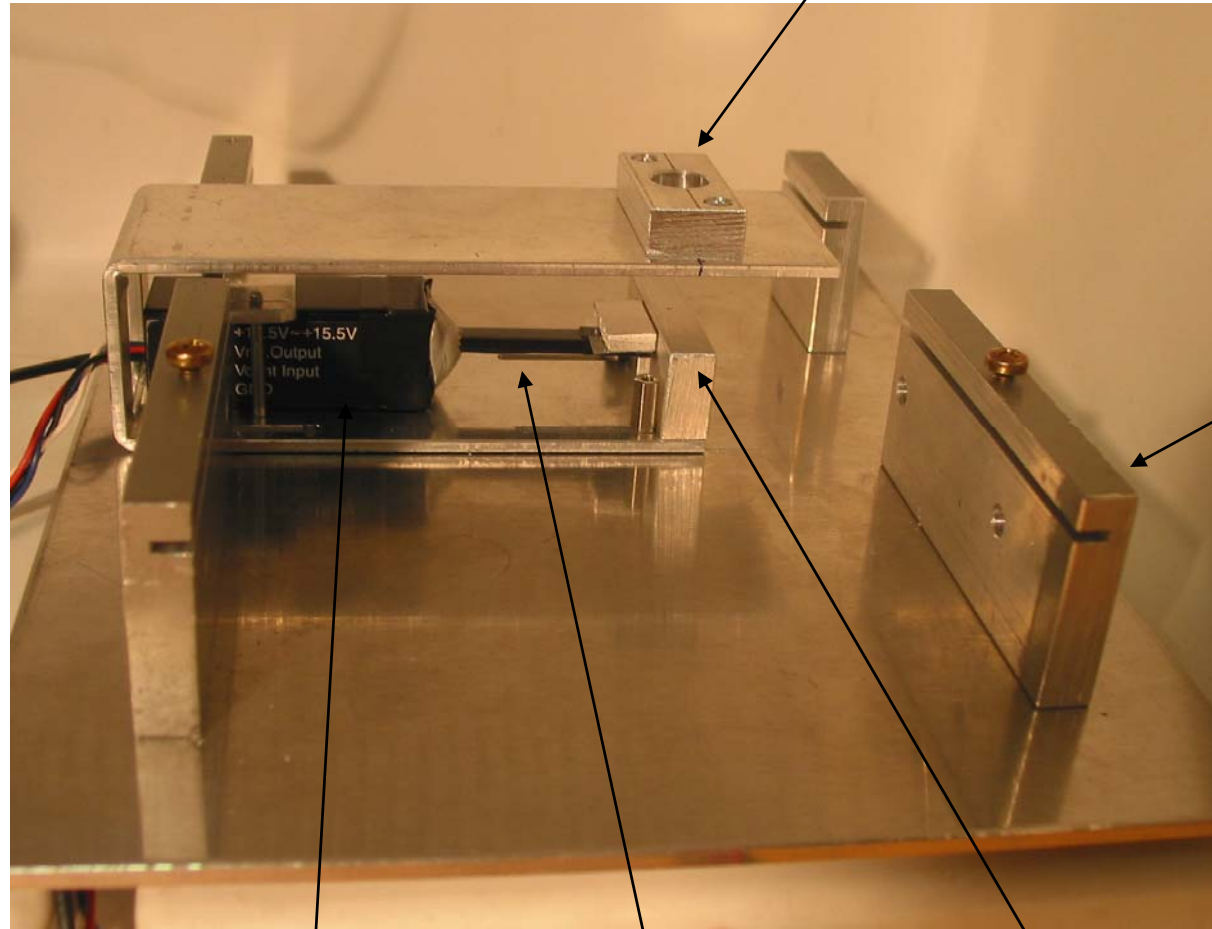
Test PCB



Aluminium support structure

- dimensions: ~ 25 cm x 20 cm x 6 cm

^{90}Sr source is inserted into the upper collimator



Test board holder

Photo Multiplier

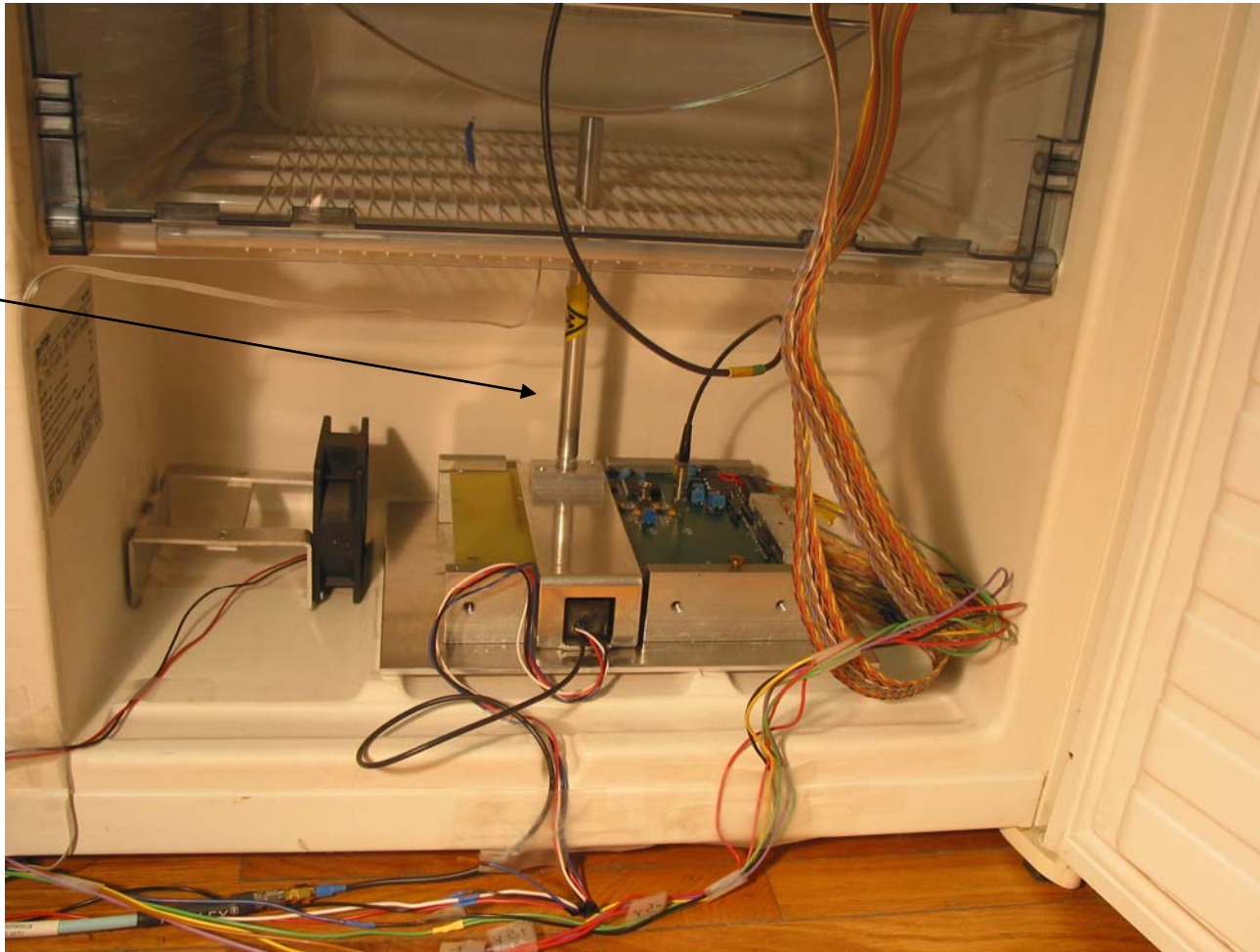
Light guide

Scintillator is under the lower collimator



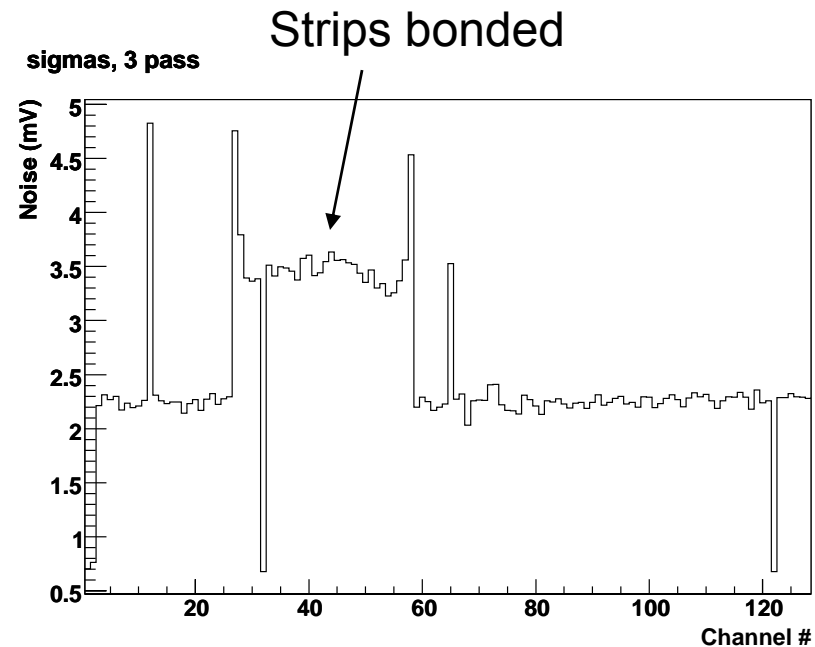
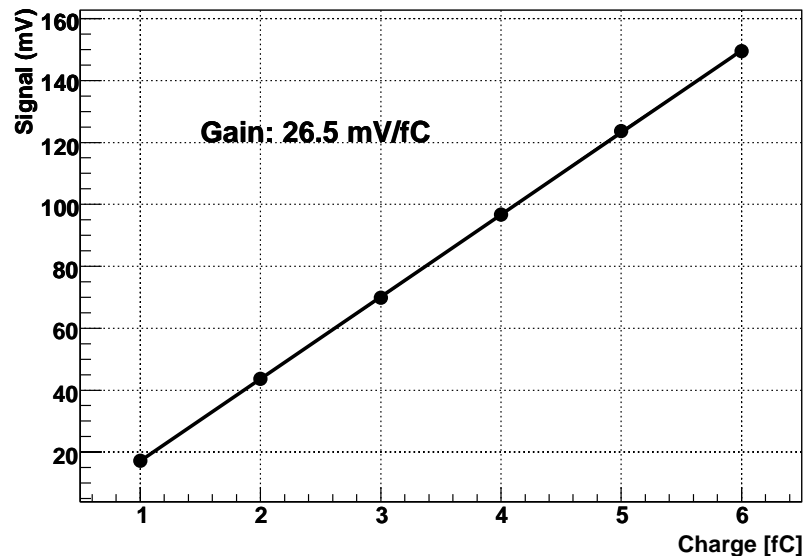
Setup in the fridge, temperature about - 20° C

^{90}Sr source holder



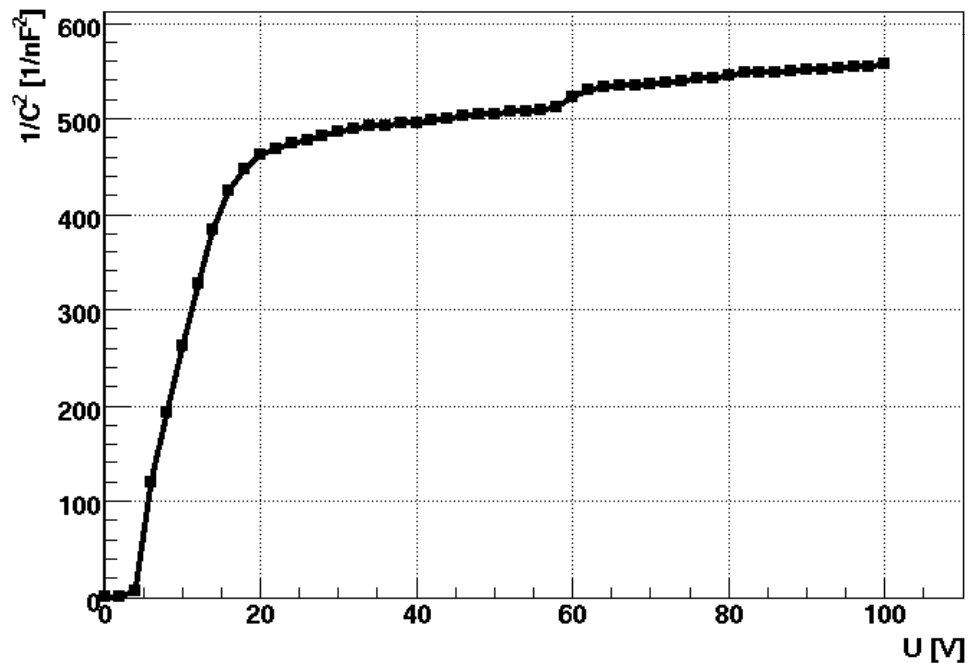
SCTA128VG chip

- 128 channels
- charge sensitive front-end amplifier with about 20 ns peaking time
- sampled every 25 ns (40 MHz sampling clock)
- Gain = 26.5 mV/fC = 4.2 μ V/el measured with calibration signals from on-chip capacitors (~ 10 % accuracy)
- noise with detector connected ~ 800 el



Detectors

- p-type, FZ material, 300 μm thick strip detectors
- strip pitch 80 μm
- n-in-p capacitively coupled
- polysilicon biased, p-sprayed
- designed by Liverpool, produced by [Micron Semiconductor](#), sent to us by [Gianluigi Casse](#)



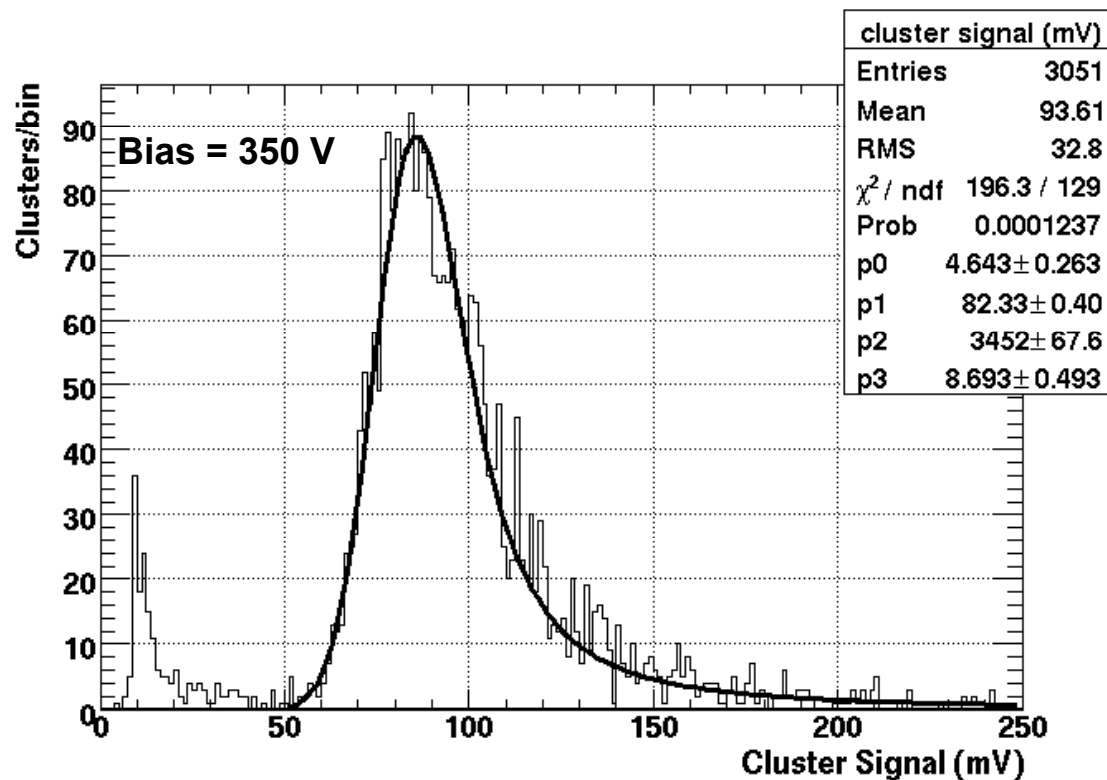
Irradiations

- detectors were irradiated with neutrons in the TRIGA reactor in Ljubljana
- 1 MeV equivalent fluences (same fluence steps as for Liverpool):
 - $5 \cdot 10^{14}$ n/cm²
 - $1.6 \cdot 10^{15}$ n/cm²
 - $3 \cdot 10^{15}$ n/cm²
- after irradiation detectors were annealed for 80 minutes at 60° C



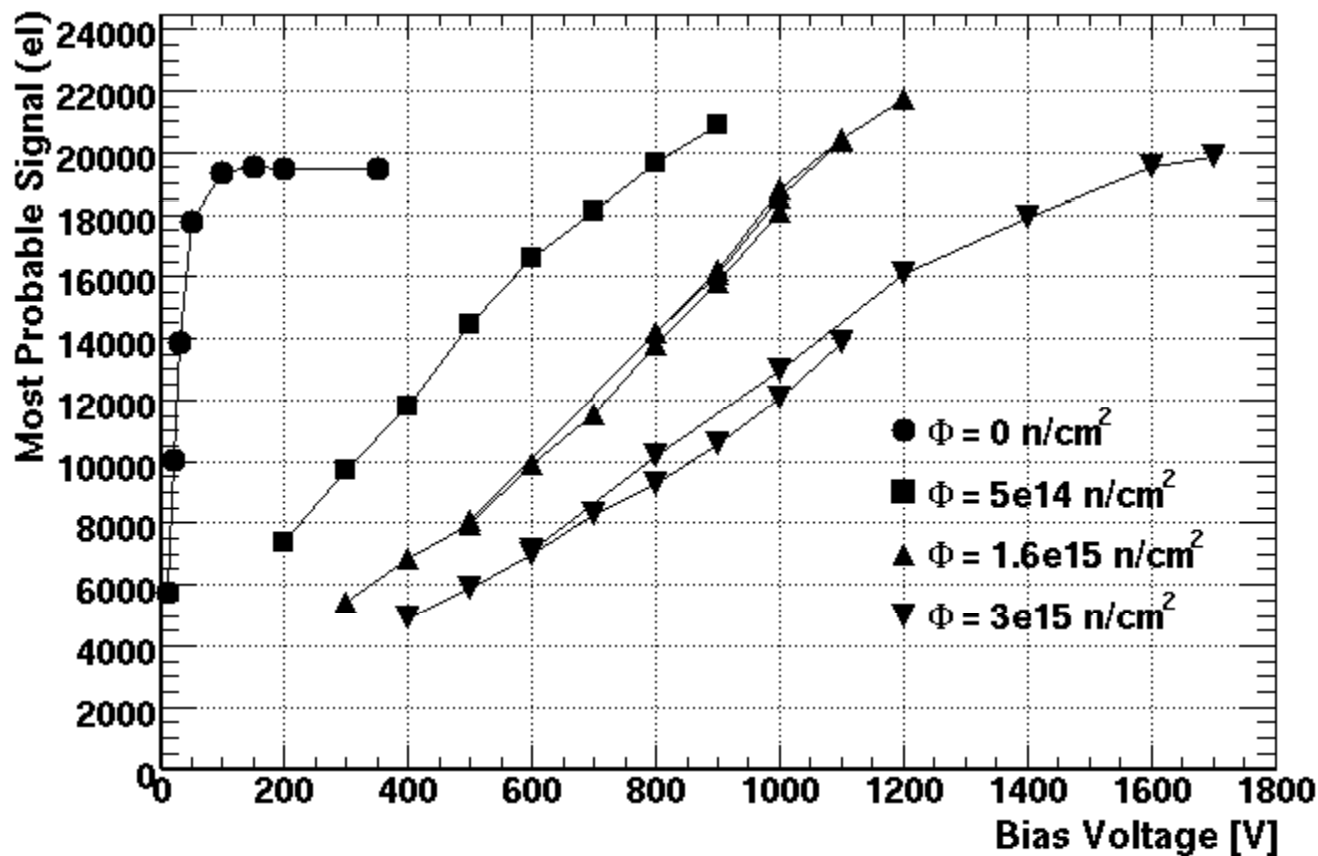
Measurements

- trigger: signals caused by electrons from ^{90}Sr source in scintillator in coincidence with 40 MHz clock edge
- spectrum of signals from strips (pedestals and common mode variations subtracted) fitted with convolution of Landau and Gauss functions
 - ➔ “Most Probable Value” of the Landau function (parameter p1 in the plot below) returned by the fit is the measure of collected charge



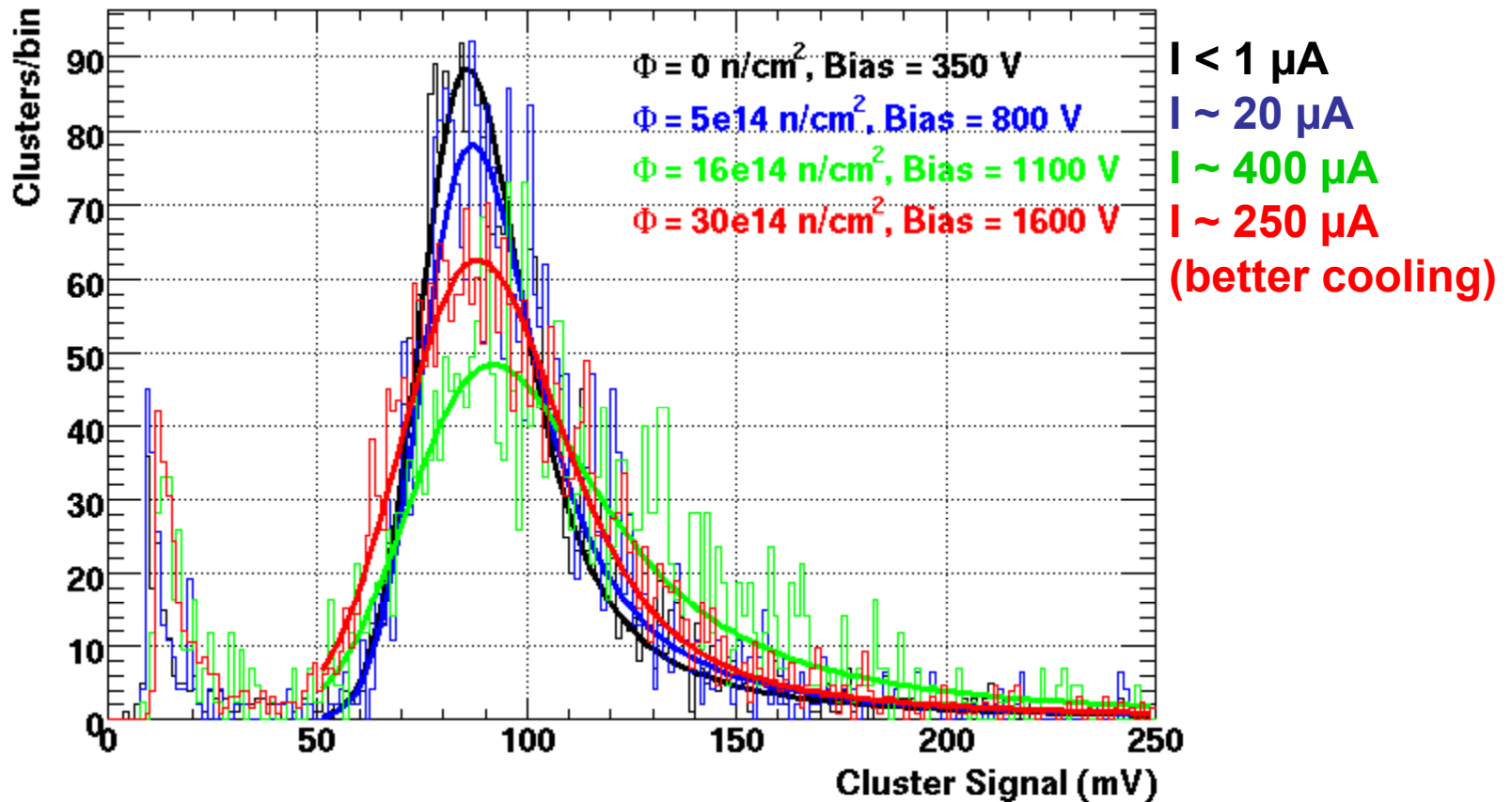
Signal vs. Bias Voltage

- measurements taken at -20°C
- statistical error of points $\sim 5\%$
- highest voltage limited by breakdown
- repeats of measurements are shown at two highest fluences (reproducibility test)



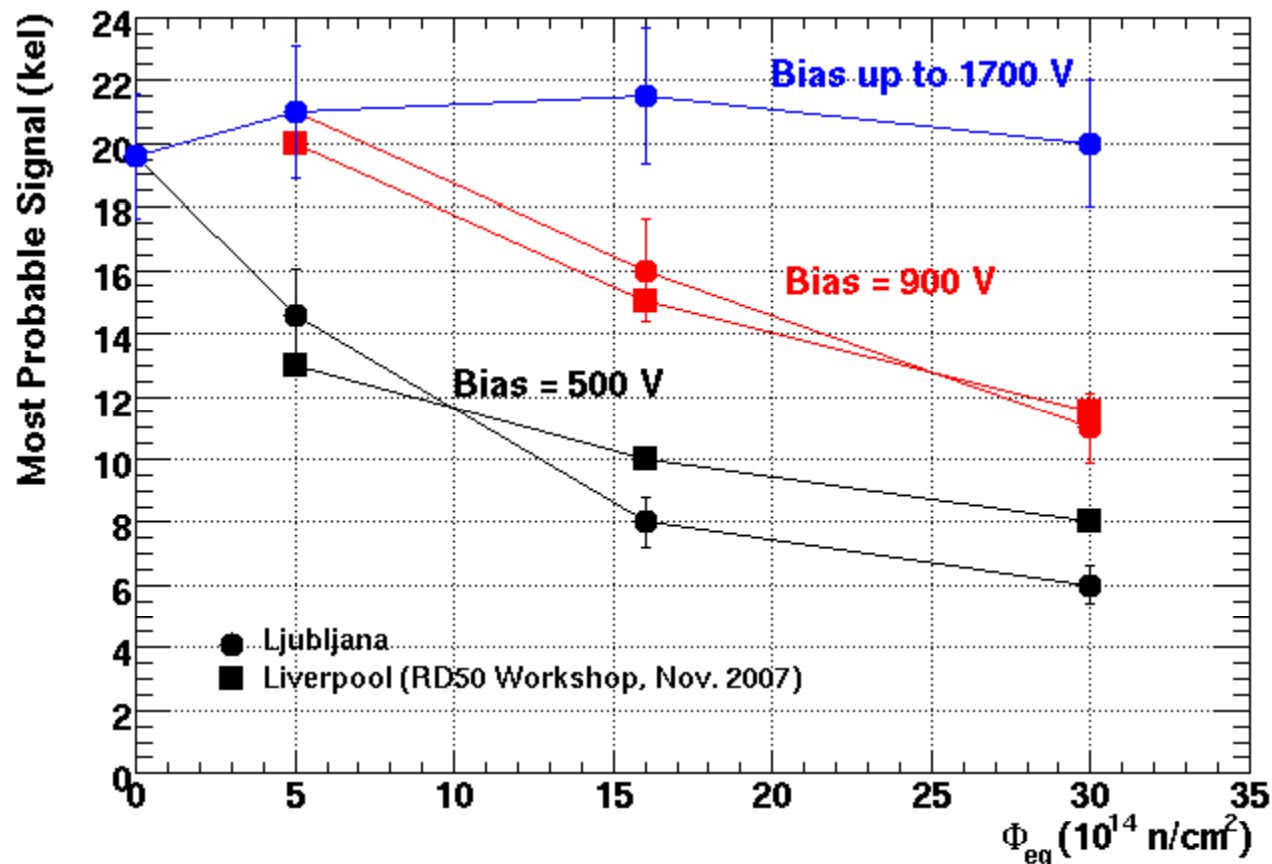
Comparison of spectra in which MP ~ 20 kel measured after different fluences (normalized to the equal number of clusters in histogram)

- signals at high voltage after irradiation as high as before irradiation



Signal vs. Fluence

- good agreement with Liverpool results
- with present cabling in ATLAS the highest voltage is 500 V
- it seems that higher bias voltage would help

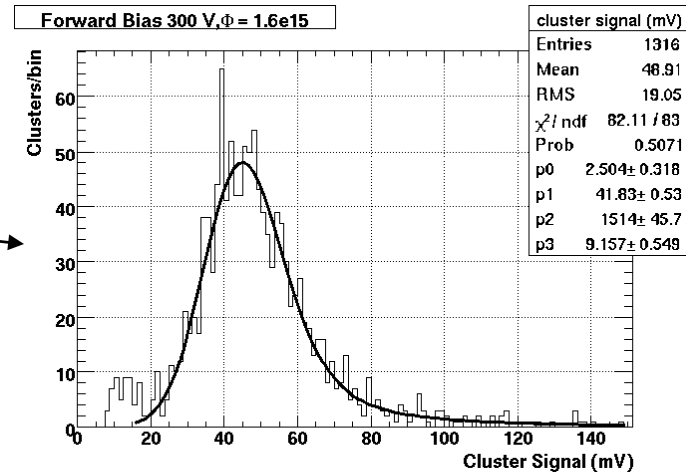


Forward Bias

- after very high fluence detectors can be operated under forward bias

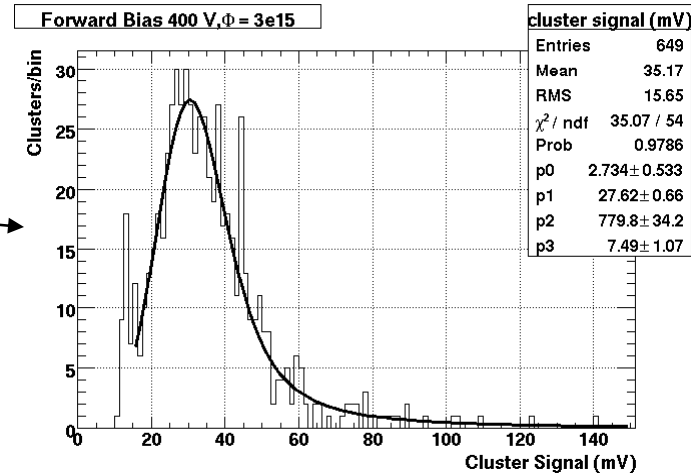
$\Phi = 1.6 \cdot 10^{15} \text{ n/cm}^2$, $T \sim -40^\circ \text{ C}$
 (a cup of liquid N_2 put into the fridge)
 Bias = +300 V, $I = 200 \mu\text{A}$,
MPV = 10 keV

Reverse bias $\sim -600 \text{ V}$ needed for same MPV, but much lower current (less than $10 \mu\text{A}$ at this T)



$\Phi = 3 \cdot 10^{15} \text{ n/cm}^2$, $T \sim -24^\circ \text{ C}$,
 Bias = +400 V, $I = 600 \mu\text{A}$,
MPV = 6.5 keV

Reverse bias $\sim -600 \text{ V}$ needed for same MPV, but much lower current ($35 \mu\text{A}$ at this T)



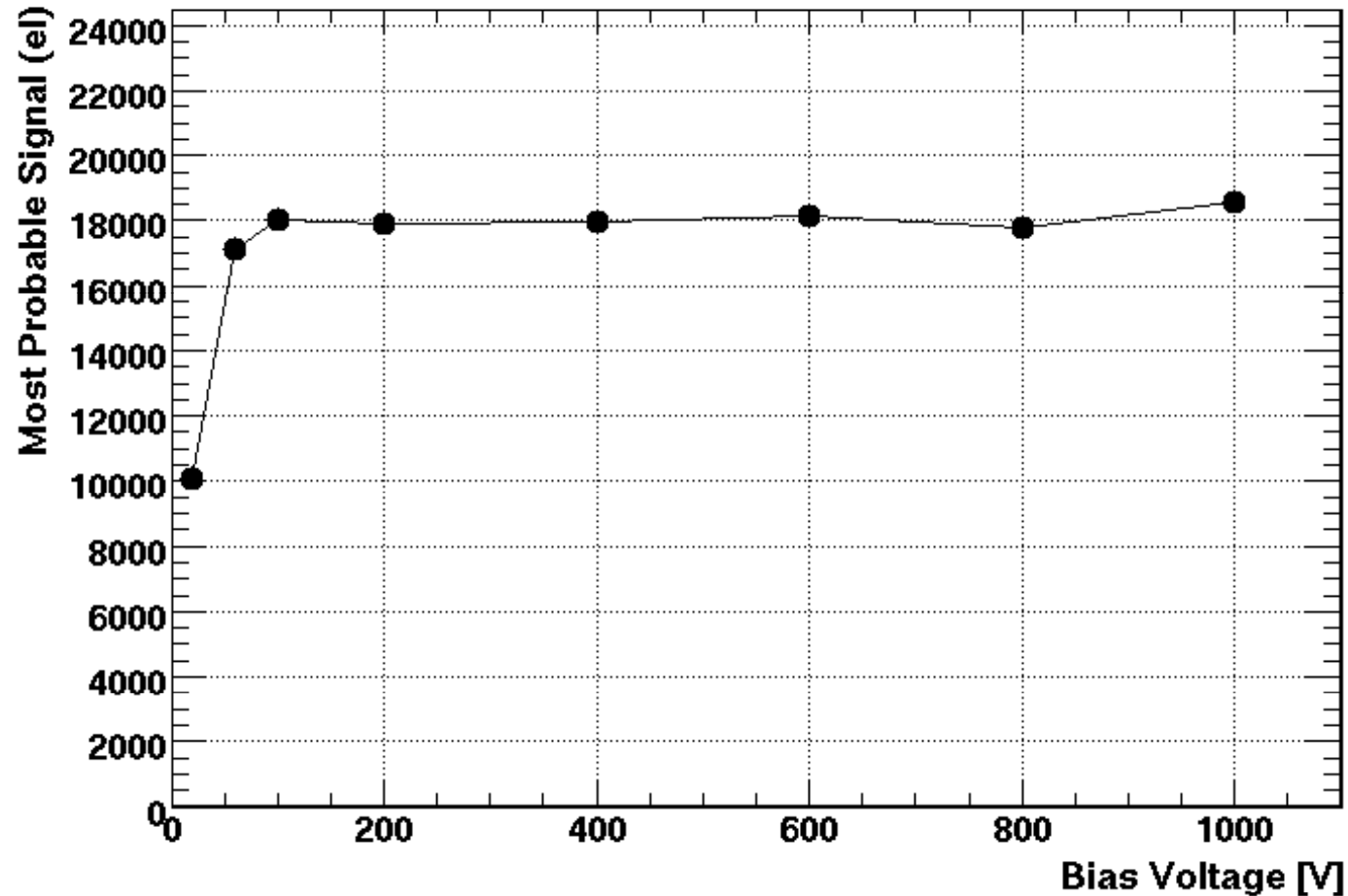
Conclusions

- signals caused by fast electrons from ^{90}Sr source in p-type microstrip detectors were measured with SCT128 chip
- measurements were made up to very high bias voltages (max. 1700 V)
- CCE as high as before irradiation measured at sufficiently high voltage in detectors irradiated up to $\Phi = 3 \cdot 10^{15} \text{ n/cm}^2$
- good agreement with measurements from Liverpool

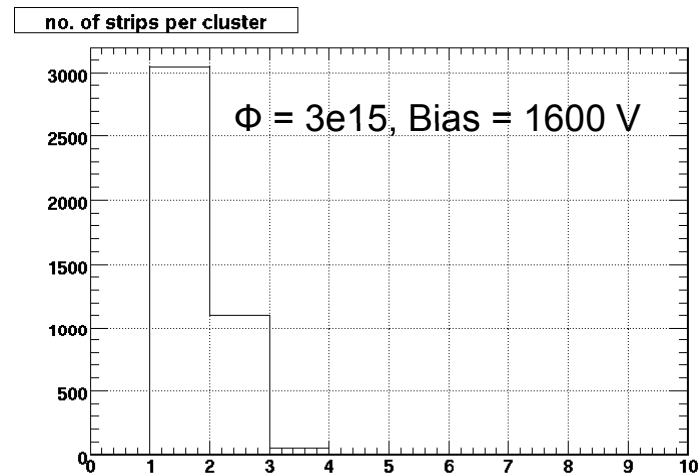
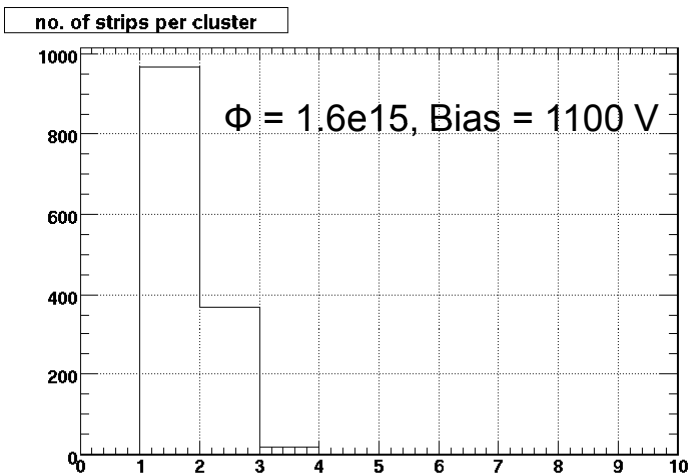
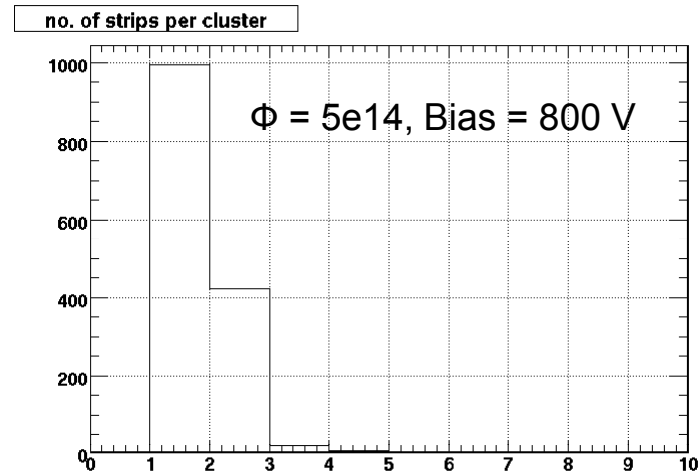
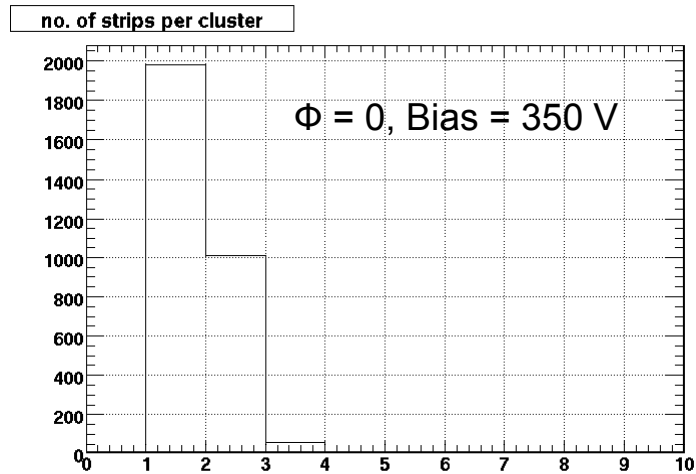


Backup plots

Modul 0, $\Phi_{\text{eq}} = 0 \text{ n/cm}^2$, exposed to few Mrads of gammas

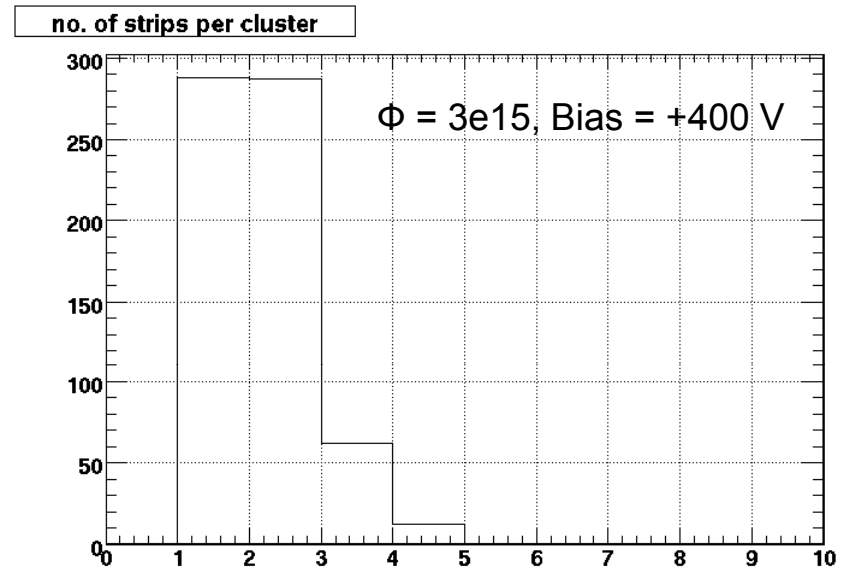
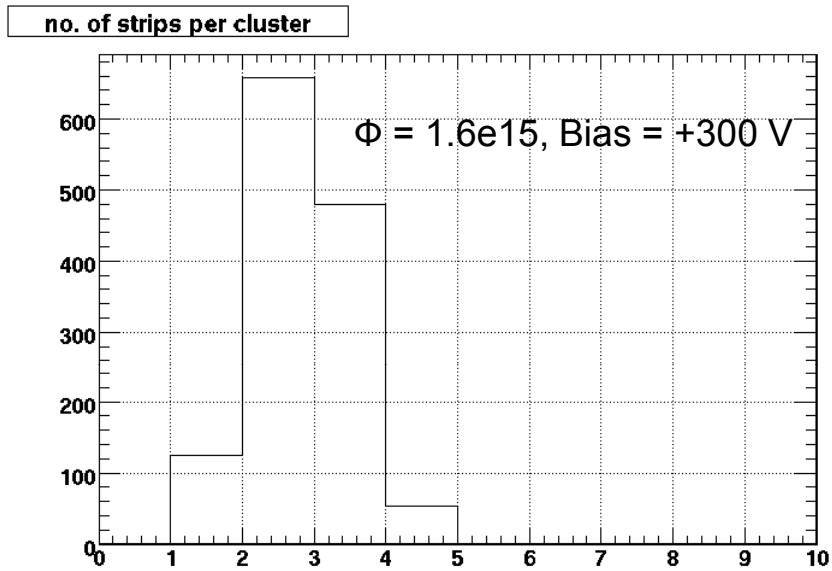


Number of strips per cluster



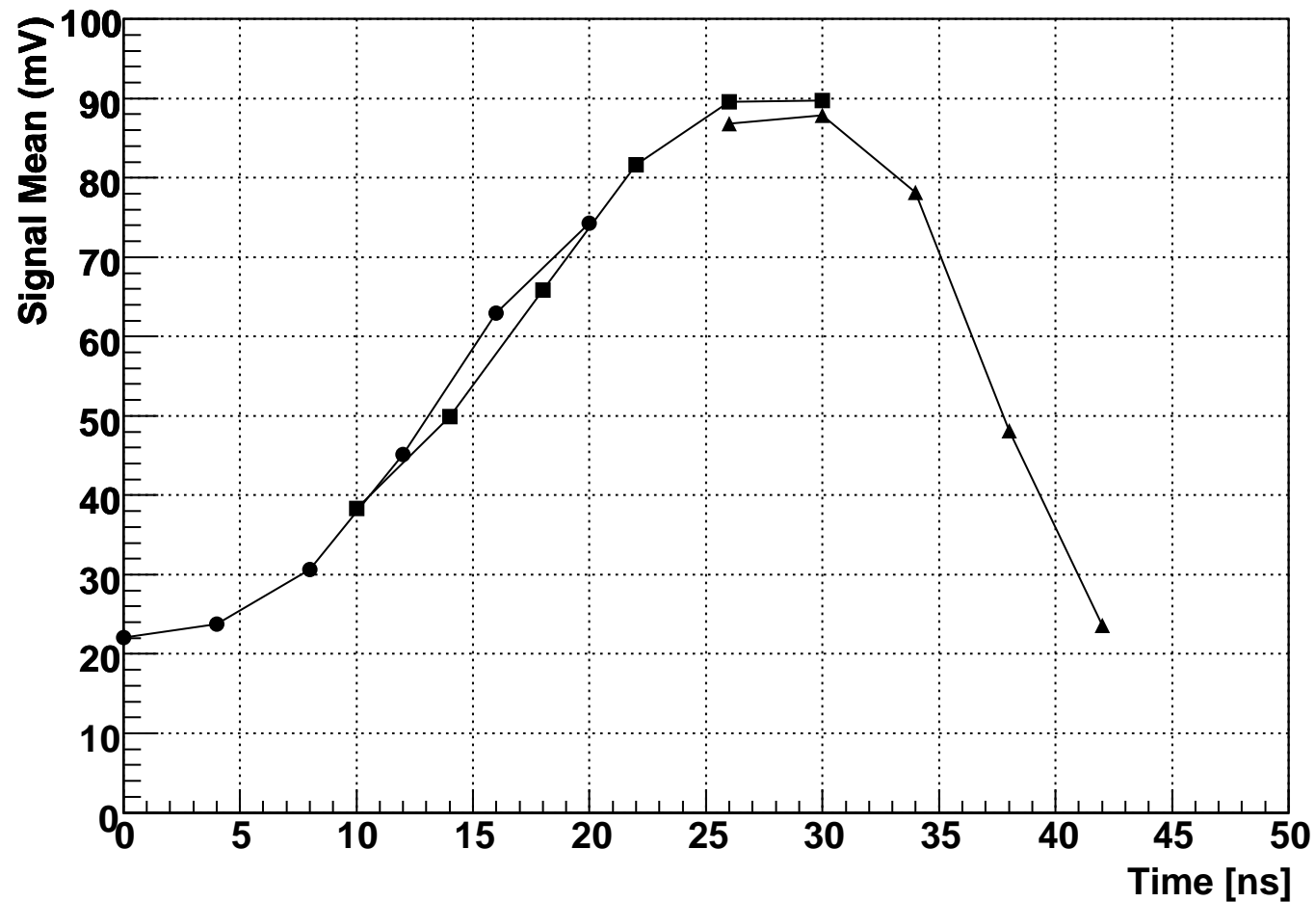
Number of strips per cluster

- forward bias



Pulse shape

- signal mean vs. trigger delay, before irradiation
- Bias = 200 V



Signal to noise

- measurements for which MPV ~ 20000 el

